NSN 5961-01-463-0850

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-463-0850 **Inclosure Material:** Ceramic **Overall Length:** 9.78 millimeters **Overall Height:** 1.80 millimeters **Overall Width:** 9.78 millimeters **End Application:** 6625-01-425-2551 **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 5.0 drain to source voltage and -6.0 gate to source voltage **Current Rating Per Characteristic:** 100.00 milliamperes drain current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**